TCA6416A Low-Voltage 16-Bit I²C and SMBus I/O Expander With Voltage Translation, Interrupt Output, Reset Input, and Configuration Registers

1 Features

- I²C to parallel port expander
- Operating power-supply voltage range of 1.65 V to 5.5 V
- Allows bidirectional voltage-level translation and GPIO expansion between 1.8-V, 2.5-V, 3.3-V, and 5-V I²C Bus and P-ports
- Low standby current consumption of 3 μA
- 5-V Tolerant I/O ports
- 400-kHz Fast I²C bus
- Hardware address pin allows two TCA6416A devices on the same I²C/SMBus bus
- Active-low reset input (RESET)
- Open-drain active-low interrupt output (INT)
- Input/output configuration register
- · Polarity inversion register
- Internal power-on reset
- Power-up with all channels configured as inputs
- · No glitch on power up
- · Noise filter on SCL and SDA inputs
- Latched outputs with high-current drive maximum capability for directly driving LEDs
- Latch-up performance exceeds 100 mA Per JESD 78, class II
- ESD Protection exceeds JESD 22
 - 2000-V Human-body model (A114-A)
 - 200-V Machine model (A115-A)
 - 1000-V Charged-device model (C101)

2 Applications

- Servers
- Routers (telecom switching equipment)
- · Personal computers
- Personal electronics (for example, gaming consoles)
- Industrial automation
- · Products with GPIO-limited processors

3 Description

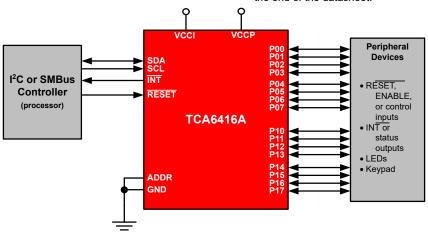
The TCA6416A is a 24-pin device that provides 16-bits of general purpose parallel input/output (I/O) expansion for the two-line bidirectional I²C bus (or SMBus) protocol. The device can operate with a power supply voltage ranging from 1.65 V to 5.5 V on the I²C bus side (VCCI) and a power supply voltage ranging from 1.65 V to 5.5 V on the P-port side (VCCP).

The device supports both 100-kHz (Standard-mode) and 400-kHz (Fast-mode) clock frequencies. I/O expanders such as the TCA6416A provide a simple solution when additional I/Os are needed for switches, sensors, push-buttons, LEDs, fans, and so forth.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)
	TSSOP (24)	7.80 mm × 4.40 mm
TCA6416A	WQFN (24)	4.00 mm × 4.00 mm
	Microstar BGA™ Junior (24)	3.00 mm × 3.00 mm

 For all available packages, see the orderable addendum at the end of the datasheet.



Simplified Schematic

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5 Pin Configuration and Functions

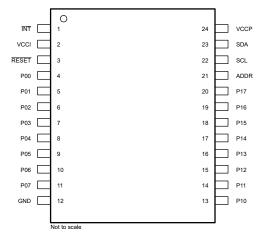


Figure 5-1. PW package, 24-Pin TSSOP (Top View)

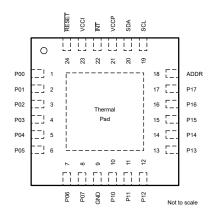


Figure 5-2. RTW Package, 24-Pin WQFN (Top View)

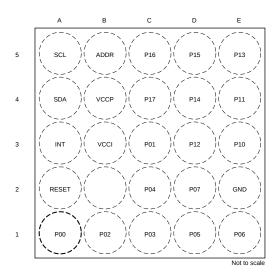


Figure 5-3. ZQS Package 24-Pin Microstar BGATM Junior (Top View)

Table 5-1. Pin Functions

	PI	IN		Table 3-1. Fift unctions
NAME	TSSOP (PW)	QFN (RTW)	BGA (ZQS)	DESCRIPTION
INT	1	22	A3	Interrupt output. Connect to V _{CCI} or V _{CCP} through a pull-up resistor.
VCCI	2	23	В3	Supply voltage of I ² C bus. Connect directly to the supply voltage of the external I ² C controller.
RESET	3	24	A2	Active-low reset input. Connect to V_{CCI} or V_{CCP} through a pull-up resistor, if no active connection is used.
P00	4	1	A1	P-port input/output (push-pull design structure). At power on, P00 is configured as an input.
P01	5	2	C3	P-port input/output (push-pull design structure). At power on, P01 is configured as an input.
P02	6	3	B1	P-port input/output (push-pull design structure). At power on, P02 is configured as an input.
P03	7	4	C1	P-port input/output (push-pull design structure). At power on, P03 is configured as an input.
P04	8	5	C2	P-port input/output (push-pull design structure). At power on, P04 is configured as an input.
P05	9	6	D1	P-port input/output (push-pull design structure). At power on, P05 is configured as an input.
P06	10	7	E1	P-port input/output (push-pull design structure). At power on, P06 is configured as an input.
P07	11	8	D2	P-port input/output (push-pull design structure). At power on, P07 is configured as an input.
GND	12	9	E2	Ground
P10	13	10	E3	P-port input/output (push-pull design structure). At power on, P10 is configured as an input.
P11	14	11	E4	P-port input/output (push-pull design structure). At power on, P11 is configured as an input.
P12	15	12	D3	P-port input/output (push-pull design structure). At power on, P12 is configured as an input.
P13	16	13	E5	P-port input/output (push-pull design structure). At power on, P13 is configured as an input.
P14	17	14	D4	P-port input/output (push-pull design structure). At power on, P14 is configured as an input.
P15	18	15	D5	P-port input/output (push-pull design structure). At power on, P15 is configured as an input.
P16	19	16	C5	P-port input/output (push-pull design structure). At power on, P16 is configured as an input.
P17	20	17	C4	P-port input/output (push-pull design structure). At power on, P17 is configured as an input.
ADDR	21	18	B5	Address input. Connect directly to V _{CCP} or ground.
SCL	22	19	A5	Serial clock bus. Connect to V _{CCI} through a pull-up resistor.
SDA	23	20	A4	Serial data bus. Connect to V _{CCI} through a pull-up resistor.
VCCP	24	21	B4	Supply voltage of TCA6416A for P-ports

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

				MIN	MAX	UNIT
V _{CCI}	Supply voltage			-0.5	6.5	V
V _{CCP}	Supply voltage	-0.5	6.5	V		
VI	Input voltage (2)			-0.5	6.5	V
Vo	Output voltage ⁽²⁾			-0.5	6.5	V
I _{IK}	Input clamp current	Input clamp current ADDR, RESET, SCL V _i < 0				mA
I _{OK}	Output clamp current	INT	V _O < 0		±20	mA
	Input/output clamp current	P port	V _O < 0 or V _O > V _{CCP}		±20	mA
I _{IOK}	inpul/output clamp current	SDA	V _O < 0 or V _O > V _{CCI}		±20	
	Continuous sutput law surrent	P port	V _O = 0 to V _{CCP}		50	A
I _{OL}	Continuous output low current	SDA, ĪNT	V _O = 0 to V _{CCI}		25	mA
I _{OH}	Continuous output high current	P port	V _O = 0 to V _{CCP}		50	mA
	Continuous current through GND				200	
I _{CC}	Continuous current through V _{CCP}				160	mA
	Continuous current through V _{CCI}				10	
_	V _{CC} ≤ 3.6 V					°C
T_J	Max junction temperature		3.6 V < V _{CC} ≤ 5.5 V		90	
T _{stg}	Storage temperature		•	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

				MIN	MAX	UNIT	
\/	Committee	-40 °C ≤ T _A :	≤ 85 °C	1.65	5.5		
V _{CCI}	Supply voltage	85 °C < T _A ≤	125 °C	1.65	3.6	V	
.,	Complement	-40 °C ≤ T _A :	≤ 85 °C	1.65	5.5	V	
V_{CCP}	Supply voltage	85 °C < T _A ≤	125 °C	1.65	3.6		
		SCL, SDA		0.7 × V _{CCI}	V _{CCI} (1)		
V_{IH}	High-level input voltage	RESET		0.7 × V _{CCI}	5.5	V	
		ADDR, P17-	-P00	0.7 × V _{CCP}	5.5		
.,	Lave lavel in motor alta an	SCL, SDA, Ī	SCL, SDA, RESET		0.3 × V _{CCI}	V	
V_{IL}	Low-level input voltage	ADDR, P17-	-P00	-0.5	0.3 × V _{CCP}	V	
I _{OH}	High-level output current	P17-P00			10	mA	
			T _J ≤ 65 °C		25		
			T _J ≤ 85 °C		18		
I_{OL}	Low-level output current	P17-P00	T _J ≤ 105 °C		9	mA	
			T _J ≤ 125 °C		4.5		
			T _J ≤ 135 °C		3.5		
_		1.65 V ≤ V _{C0}	c ≤ 3.6 V	-40	125	°C	
T _A	Operating free-air temperature	3.6 V < V _{CC}	≤ 5.5 V	-40	85	C	

⁽¹⁾ The SCL and SDA pins shall not be at a higher potential than the supply voltage V_{CCI} in the application, or an increase in current consumption will result.

6.4 Thermal Information

	THERMAL METRIC ⁽¹⁾		RTW (WQFN)	ZQS (BGA MICROSTAR JUNIOR)	UNIT
		24 PINS	24 PINS	24 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	108.8	43.6	159.2	°C/W
R ₀ JC(top)	Junction-to-case (top) thermal resistance	54.0	46.2	138.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	62.8	22.1	93.6	°C/W
ΨЈТ	Junction-to-top characterization parameter	11.1	1.5	10.7	°C/W
ΨЈВ	Junction-to-board characterization parameter	62.3	22.2	95.7	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	10.7	N/A	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Electrical Characteristics

over recommended operating free-air temperature range, V_{CCI} = 1.65 V to 5.5 V (unless otherwise noted)

	METER	TEST CONDITIONS		V _{CCP}	MIN	TYP ⁽¹⁾	MAX	UNIT	
V _{IK}	Input diode clamp voltage	I _I = -18 mA		1.65 V to 5.5 V	-1.2			V	
V _{POR}	Power-on reset voltage	$V_I = V_{CCP}$ or GND, $I_O = 0$		1.65 V to 5.5 V		1	1.4	V	
				1.65 V	1.2				
		I _{OH} = -8 mA		2.3 V	1.8				
				3 V	2.6				
	P-port high-			4.5 V	4.1				
V_{OH}	level output		85 °C < T _A ≤ 125 °C	1.65 V	1.0			V	
	voltage		-40 °C ≤ T _A ≤ 85 °C	1.05 V	1.1				
		I _{OH} = -10 mA	-40 °C ≤ T _A ≤ 125 °C	2.3 V	1.7				
			-40 C S IA S 125 C	3 V	2.5				
			-40 °C ≤ T _A ≤ 85 °C	4.5 V	4.0				
				1.65 V			0.45		
			-40 °C ≤ T _A ≤ 125 °C	2.3 V			0.25		
		I _{OL} = 8 mA		3 V			0.25		
V_{OL}	P-port low-		-40 °C ≤ T _A ≤ 85 °C	4.5 V		-	0.2		
	level output voltage			1.65 V			0.6	V	
			-40 °C ≤ T _A ≤ 125 °C	2.3 V			0.3		
		I _{OL} = 10 mA		3 V			0.25		
			-40 °C ≤ T _A ≤ 85 °C	4.5 V			0.2		
	SDA	V _{OL} = 0.4 V		1.65 V to 5.5 V	3				
I _{OL}	ĪNT	V _{OL} = 0.4 V		1.65 V to 5.5 V	3	15		mA	
I _I	SCL, SDA, RESET	V _I = V _{CCI} or GND		1.65 V to 5.5 V			±0.1	μA	
,	ADDR	V _I = V _{CCP} or GND	= V _{CCP} or GND				±0.1	·	
I _{IH}	P port	V _I = V _{CCP}					1	μA	
I _{IL}	P port	V _I = GND		1.65 V to 5.5 V			1	μA	
		V_I on SDA and \overline{RESET} =		3.6 V to 5.5 V		10	20		
		V _{CCI} or GND,	-40 °C ≤ T _A ≤ 85 °C	2.3 V to 3.6 V		6.5	15		
	Operating	V _I on P port and ADDR =		1.65 V to 2.3 V		4	9		
	mode	V_{CCP} , $I_{O} = 0$, I/O = inputs,		2.3 V to 3.6 V			40		
I _{CC}		f _{SCL} = 400 kHz	85 °C < T _A ≤ 125 °C	1.65 V to 2.3 V			35		
(I _{CCI} + I _{CCP})		V _I on SCL, SDA and		3.6 V to 5.5 V		1.5	7	μA	
		RESET= V _{CCI} or GND,	-40 °C ≤ T _A ≤ 85 °C	2.3 V to 3.6 V		1	3.2		
	Standby	V _I on P port and ADDR =	^	1.65 V to 2.3 V		0.5	1.7		
	mode	V_{CCP} , $I_O = 0$, I/O = inputs,		2.3 V to 3.6 V			10		
		f _{SCL} = 0	85 °C < T _A ≤ 125 °C	1.65 V to 2.3 V			7		
	SCL, SDA, ADDR	Input at V _{CCI} – 0.6 V, Other inputs at V _{CCI} or GN	ID				25		
ΔI _{CCI}	RESET	RESET at V _{CCI} – 0.6 V, Other inputs at V _{CCI} or GN		1.65 V to 5.5 V			55	μA	
ΔI _{CCP}	P port	One input at Voca – 0.6 V					80		
C _i	SCL	V _I = V _{CCI} or GND		1.65 V to 5.5 V		6	7	pF	

6.5 Electrical Characteristics (continued)

over recommended operating free-air temperature range, V_{CCI} = 1.65 V to 5.5 V (unless otherwise noted)

PARAMETER		METER	TEST CONDITIONS	V _{CCP}	MIN TYP(1)	MAX	UNIT
C		SDA	$V_{IO} = V_{CCI}$ or GND	1.65 V to 5.5 V	7	8	nE
Cio		P port	V _{IO} = V _{CCP} or GND	1.05 V tO 5.5 V	7.5	8.5	рF

⁽¹⁾ Except for I_{CC} , all typical values are at nominal supply voltage (1.8-V, 2.5-V, 3.3-V, or 5-V V_{CC}) and T_A = 25°C. For I_{CC} , the typical values are at V_{CCP} = V_{CCI} = 3.3 V and T_A = 25°C.

6.6 I²C Interface Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 7-1)

		STANDARD MODE I ² C BUS		FAST MODE I ² C BUS		UNIT
		MIN	MAX	MIN	MAX	
f _{scl}	I ² C clock frequency	0	100	0	400	kHz
t _{sch}	I ² C clock high time	4		0.6		μs
t _{scl}	I ² C clock low time	4.7		1.3		μs
t _{sp}	I ² C spike time	0	50	0	50	ns
t _{sds}	I ² C serial data setup time	250		100		ns
t _{sdh}	I ² C serial data hold time	0		0		ns
t _{icr}	I ² C input rise time		1000	20 + 0.1C _b ⁽¹⁾	300	ns
t _{icf}	I ² C input fall time		300	20 + 0.1C _b ⁽¹⁾	300	ns
t _{ocf}	I ² C output fall time; 10 pF to 400 pF bus		300	20 + 0.1C _b ⁽¹⁾	300	μs
t _{buf}	I ² C bus free time between Stop and Start	4.7		1.3		μs
t _{sts}	I ² C Start or repeater Start condition setup time	4.7		0.6		μs
t _{sth}	I ² C Start or repeater Start condition hold time	4		0.6		μs
t _{sps}	I ² C Stop condition setup time	4		0.6		μs
t _{vd(data)}	Valid data time; SCL low to SDA output valid		1		0.9	μs
t _{vd(ack)}	Valid data time of ACK condition; ACK signal from SCL low to SDA (out) low		1		0.9	μs

⁽¹⁾ C_b = total capacitance of one bus line in pF

6.7 Reset Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 7-4)

	<u>'</u>	 				
		STANDARD MODE I ² C BUS		FAST MODE I ² C BUS		UNIT
		MIN	MAX	MIN	MAX	
t _W	Reset pulse duration	4		4		ns
t _{REC}	Reset recovery time	0		0		ns
t _{RESET}	Time to reset ⁽¹⁾	600		600		ns

⁽¹⁾ Minimum time for SDA to become high or minimum time to wait before doing a START

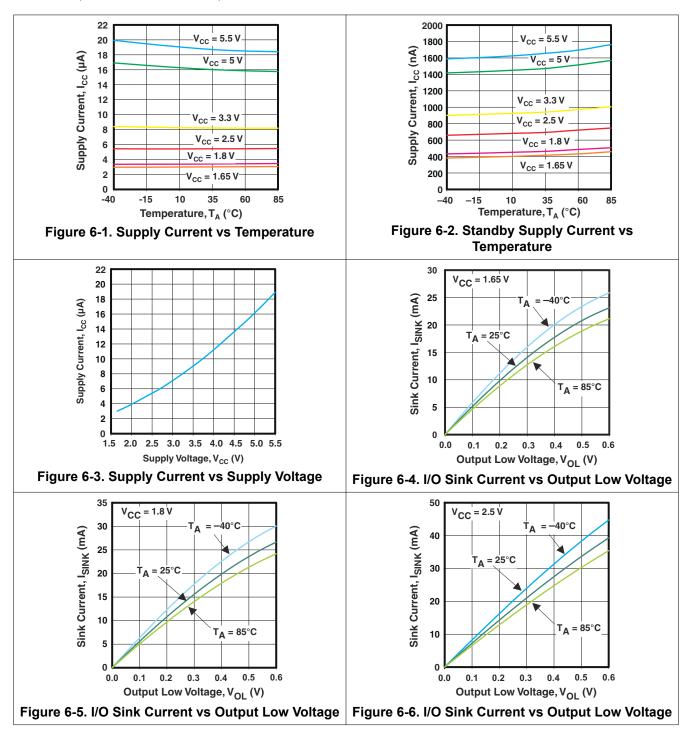
6.8 Switching Characteristics

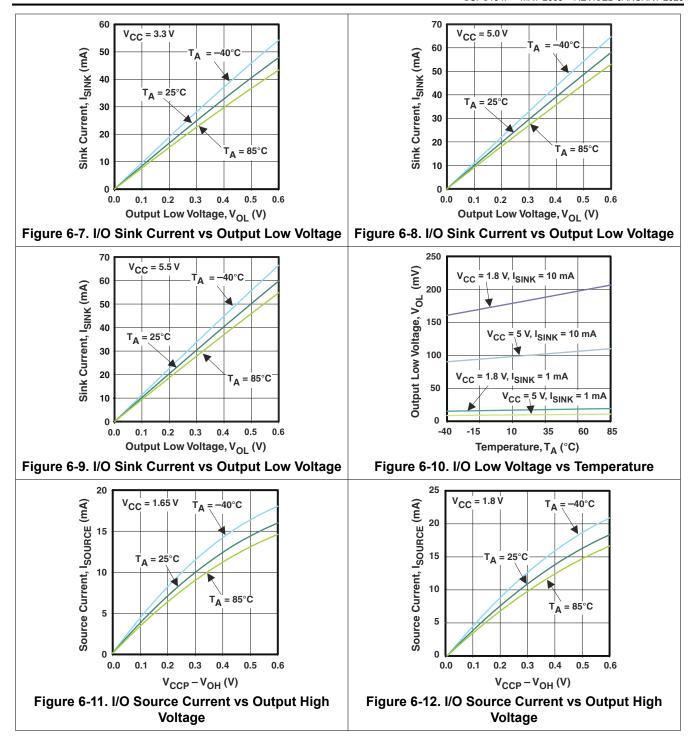
over recommended operating free-air temperature range, $C_L \le 100 \text{ pF}$ (unless otherwise noted) (see Figure 7-1)

PARAMETER		PARAMETER FROM		STANDARD MODE I ² C BUS	FAST MODE I ² C BUS	UNIT
				MIN MA	X MIN MA	X
t _{IV}	Interrupt valid time	P port	ĪNT		4	4 µs
t _{IR}	Interrupt reset delay time	SCL	ĪNT		4	4 µs
t _{PV}	Output data valid	SCL	P7–P0	40	00 40	0 ns
t _{PS}	Input data setup time	P port	SCL	0	0	ns
t _{PH}	Input data hold time	P port	SCL	300	300	ns

6.9 Typical Characteristics

T_A = 25°C (unless otherwise noted)





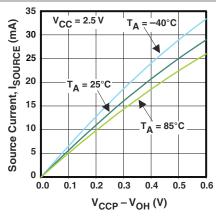


Figure 6-13. I/O Source Current vs Output High Voltage

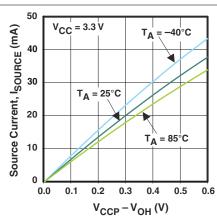


Figure 6-14. I/O Source Current vs Output High Voltage

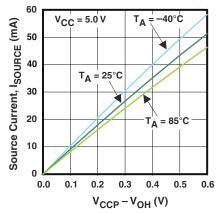


Figure 6-15. I/O Source Current vs Output High Voltage

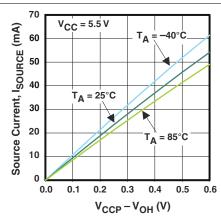


Figure 6-16. I/O Source Current vs Output High Voltage

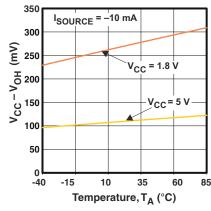
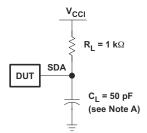
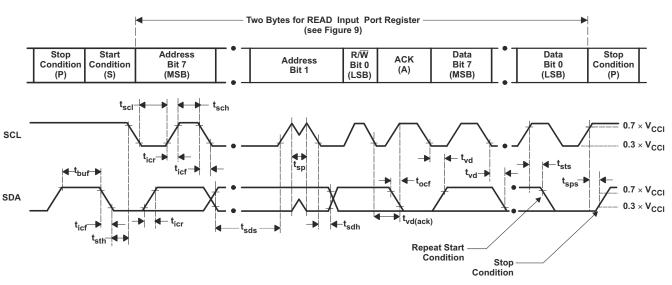


Figure 6-17. I/O High Voltage vs Temperature

7 Parameter Measurement Information



SDA LOAD CONFIGURATION

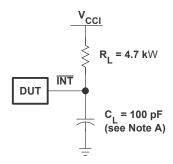


VOLTAGE WAVEFORMS

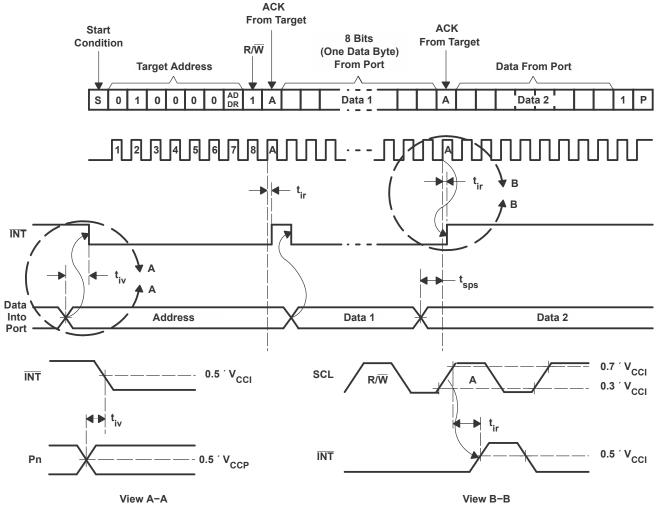
BYTE	DESCRIPTION
1	I ² C address
2	Input register port data

- A. C_L includes probe and jig capacitance, toof is measured with C_L of 10 pF or 400 pF.
- B. All inputs are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r/t_f \leq$ 30 ns.
- C. All parameters and waveforms are not applicable to all devices.

Figure 7-1. I²C Interface Load Circuit And Voltage Waveforms

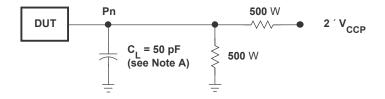


INTERRUPT LOAD CONFIGURATION

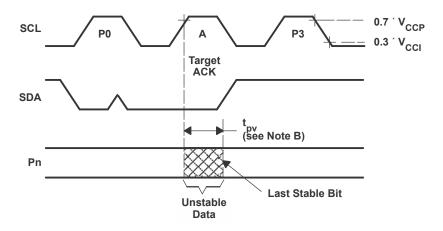


- A. C_L includes probe and jig capacitance.
- B. All inputs are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , $t_r/t_f \leq$ 30 ns.
- C. All parameters and waveforms are not applicable to all devices.

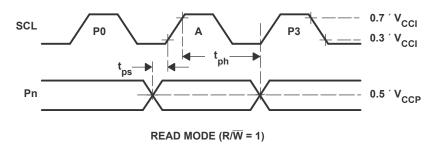
Figure 7-2. Interrupt Load Circuit and Voltage Waveforms



P-PORT LOAD CONFIGURATION

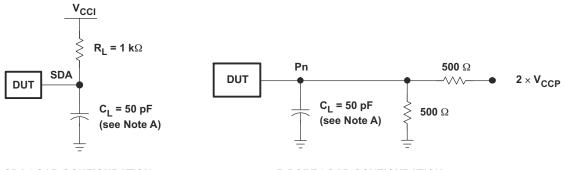


WRITE MODE $(R/\overline{W} = 0)$



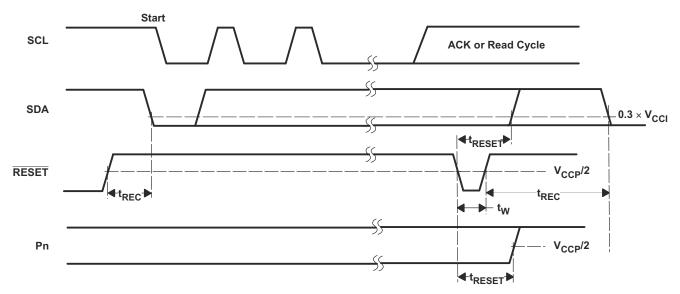
- A. C_L includes probe and jig capacitance.
- B. t_{pv} is measured from 0.7 × V_{CC} on SCL to 50% I/O (Pn) output.
- C. All inputs are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , $t_r/t_f \leq$ 30 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 7-3. P-Port Load Circuit and Timing Waveforms



SDA LOAD CONFIGURATION

P-PORT LOAD CONFIGURATION



- A. C_L includes probe and jig capacitance.
- B. All inputs are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , $t_r/t_f \leq$ 30 ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. I/Os are configured as inputs.
- E. All parameters and waveforms are not applicable to all devices.

Figure 7-4. Reset Load Circuits and Voltage Waveforms

8 Detailed Description

8.1 Overview

The TCA6416A is a 16-bit I/O expander for the two-line bidirectional bus (I²C) is designed for 1.65-V to 5.5-V operation. It provides general-purpose remote I/O expansion and bidirectional voltage translation for processors through I²C communication, an interface consisting of serial clock (SCL), and serial data (SDA) signals.

The major benefit of the TCA6416A is its voltage translation capability over a of a wide supply voltage range. This allows the TCA6416A to interface with modern processors on the I²C side, where supply levels are lower to conserve power. In contrast to the dropping power supplies of processors, some PCB components such as LEDs, still require a 5-V power supply.

The VCCI pin is the power supply for the I^2C bus, and therefore the pull-up resistors connected to the SCL, SDA, INT, and RESET pins should be terminated at V_{CCI} on the opposite side. level of the I^2C bus to the TCA6416A. The VCCP pin is the power supply for the P-ports and if pull-up resistors are used on any P-port or LEDs are driven by any P-port, then the resistor(s) or LED(s) connected to P00-P07 and P10-P17 should be terminated at V_{CCP} on the opposite side. The device P-ports configured as outputs have the ability to sink up to 25 mA for directly driving LEDs, but the current must be limited externally with an additional resistance.

The features of the device include an interrupt that is generated on the $\overline{\text{INT}}$ pin whenever an input port changes state. The devices can also be reset to its default state by applying a low logic level to the $\overline{\text{RESET}}$ pin or by cycling power to the device and causing a power-on reset. The ADDR hardware selectable address pin allows two TCA6416A devices to be connected to the same I²C bus.

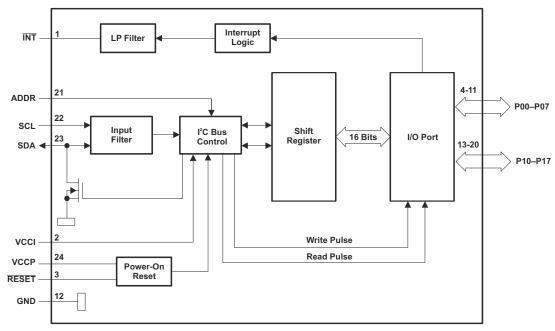
The TCA6416A open-drain interrupt ($\overline{\text{INT}}$) output is activated when any input state differs from its corresponding Input Port register state and is used to indicate to the system controller that an input state has changed. The $\overline{\text{INT}}$ pin can be connected to the interrupt input of a processor. By sending an interrupt signal on this line, the TCA6416A can inform the processor if there is incoming data on the remote I/O ports without having to communicate via the I²C bus. Thus, the TCA6416A can remain a simple target device.

The system controller can reset the TCA6416A in the event of a timeout or other improper operation by asserting a low on the $\overline{\text{RESET}}$ input pin or by cycling the power to the VCCP pin and causing a power-on reset (POR). A reset puts the registers in their default state and initializes the I²C /SMBus state machine. The $\overline{\text{RESET}}$ feature and a POR cause the same reset/initialization to occur, but the $\overline{\text{RESET}}$ feature does so without powering down the part.

One hardware pin (ADDR) can be used to program and vary the fixed I^2C address and allow two devices to share the same I^2C bus or SMBus.

The TCA6416A's digital core consists of eight 8-bit data registers: two Configuration registers (input or output selection), two Input Port registers, two Output Port registers, and two Polarity Inversion registers. At power on or after a reset, the I/Os are configured as inputs. However, the system controller can configure the I/Os as either inputs or outputs by writing to the Configuration registers. The data for each input or output is kept in the corresponding Input Port or Output Port register. The polarity of the Input Port register can be inverted with the Polarity Inversion register. All registers can be read by the system controller.

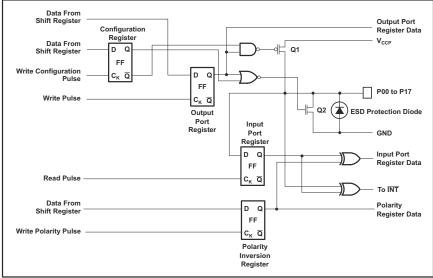
8.2 Functional Block Diagrams



- All I/Os are set to inputs at reset.
- B. Pin numbers shown are for the PW package.

Figure 8-1. Logic Diagram (Positive Logic)

Data From Shift Register



A. On power up or reset, all registers return to default values.

Figure 8-2. Simplified Schematic of P0 to P17

8.3 Feature Description

8.3.1 Voltage Translation

Table 8-1 lists all of the optional voltage supply level combinations for the I^2C bus (V_{CCI}) and the P-ports (V_{CCP}) supported by the TCA6416A.

Table 8-1. Voltage Translation

V _{CCI} (SDA AND SCL OF I ² C CONTROLLER) (V)	V _{CCP} (P-PORTS) (V)
1.8	1.8
1.8	2.5
1.8	3.3
1.8	5
2.5	1.8
2.5	2.5
2.5	3.3
2.5	5
3.3	1.8
3.3	2.5
3.3	3.3
3.3	5
5	1.8
5	2.5
5	3.3
5	5

8.3.2 I/O Port

When an I/O is configured as an input, FETs Q1 and Q2 are off, which creates a high-impedance input. The input voltage may be raised above V_{CC} to a maximum of 5.5 V.

If the I/O is configured as an output, Q1 or Q2 is enabled, depending on the state of the output port register. In this case, there are low-impedance paths between the I/O pin and either V_{CC} or GND. The external voltage applied to this I/O pin should not exceed the recommended levels for proper operation.

8.3.3 Interrupt Output (INT)

An interrupt is generated by any rising or falling edge of the port inputs in the input mode. After time t_{iv} , the signal \overline{INT} is valid. Resetting the interrupt circuit is achieved when data on the port is changed to the original setting or when data is read from the port that generated the interrupt. Resetting occurs in the read mode at the acknowledge (ACK) or not acknowledge (NACK) bit after the rising edge of the SCL signal. Interrupts that occur during the ACK or NACK clock pulse can be lost (or be very short) due to the resetting of the interrupt during this pulse. Each change of the I/Os after resetting is detected and is transmitted as \overline{INT} .

Reading from or writing to another device does not affect the interrupt circuit, and a pin configured as an output cannot cause an interrupt. Changing an I/O from an output to an input may cause a false interrupt to occur, if the state of the pin does not match the contents of the Input Port register.

The $\overline{\text{INT}}$ output has an open-drain structure and requires pull-up resistor to V_{CCP} or V_{CCI} depending on the application. $\overline{\text{INT}}$ should be connected to the voltage source of the device that requires the interrupt information.

8.3.4 Reset Input (RESET)

The $\overline{\text{RESET}}$ input can be asserted to initialize the system while keeping the V_{CCP} at its operating level. A reset can be accomplished by holding the $\overline{\text{RESET}}$ pin low for a minimum of t_W . The TCA6416A registers and I²C/SMBus state machine are changed to their default state once $\overline{\text{RESET}}$ is low (0). When $\overline{\text{RESET}}$ is high (1), the I/O levels at the P port can be changed externally or through the controller. This input requires a pull-up resistor to V_{CCI}, if no active connection is used.

8.4 Device Functional Modes

8.4.1 Power-On Reset

When power (from 0 V) is applied to V_{CCP} , an internal power-on reset holds the TCA6416A in a reset condition until V_{CCP} has reached V_{POR} . At that time, the reset condition is released, and the TCA6416A registers and $I^2C/SMBus$ state machine initializes to their default states. After that, V_{CCP} must be lowered to below V_{PORF} and back up to the operating voltage for a power-reset cycle.

8.5 Programming

8.5.1 I²C Interface

The bidirectional I²C bus consists of the serial clock (SCL) and serial data (SDA) lines. Both lines must be connected to a positive supply through a pull-up resistor when connected to the output stages of a device. Data transfer may be initiated only when the bus is not busy.

I²C communication with this device is initiated by a controller sending a Start condition, a high-to-low transition on the SDA input/output, while the SCL input is high (see Figure 8-3). After the Start condition, the device address byte is sent, most significant bit (MSB) first, including the data direction bit (R/ \overline{W}).

After receiving the valid address byte, this device responds with an acknowledge (ACK), a low on the SDA input/output during the high of the ACK-related clock pulse. The address (ADDR) input of the target device must not be changed between the Start and the Stop conditions.

On the I²C bus, only one data bit is transferred during each clock pulse. The data on the SDA line must remain stable during the high pulse of the clock period, as changes in the data line at this time are interpreted as control commands (Start or Stop) (see Figure 8-4).

A Stop condition, a low-to-high transition on the SDA input/output while the SCL input is high, is sent by the controller (see Figure 8-3).

Any number of data bytes can be transferred from the transmitter to receiver between the Start and the Stop conditions. Each byte of eight bits is followed by one ACK bit. The transmitter must release the SDA line before the receiver can send an ACK bit. The device that acknowledges must pull down the SDA line during the ACK clock pulse, so that the SDA line is stable low during the high pulse of the ACK-related clock period (see Figure 8-5). When a target receiver is addressed, it must generate an ACK after each byte is received. Similarly, the controller must generate an ACK after each byte that it receives from the target transmitter. Setup and hold times must be met to ensure proper operation.

A controller receiver signals an end of data to the target transmitter by not generating an acknowledge (NACK) after the last byte has been clocked out of the target. This is done by the controller receiver by holding the SDA line high. In this event, the transmitter must release the data line to enable the controller to generate a Stop condition.

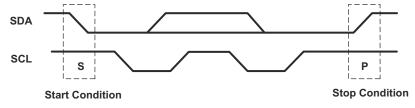


Figure 8-3. Definition of Start and Stop Conditions

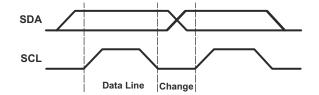


Figure 8-4. Bit Transfer

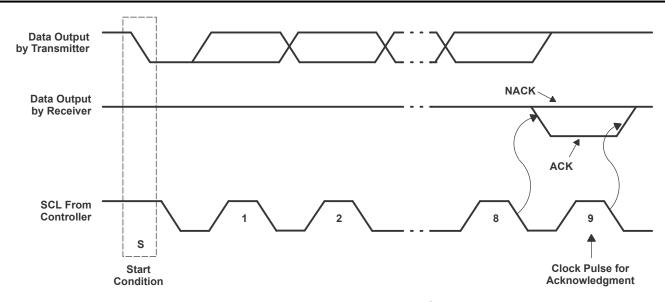


Figure 8-5. Acknowledgment on the I²C Bus

Table 8-2. Interface Definition

ВУТЕ				В	IT			
	7 (MSB)	6	5	4	3	2	1	0 (LSB)
I ² C target address	L	Н	L	L	L	L	ADDR	R/W
I/O data bus	P07	P06	P05	P04	P03	P02	P01	P00
I/O data bus	P17	P16	P15	P14	P13	P12	P11	P10

8.6 Register Maps

8.6.1 Device Address

The address of the TCA6416A is shown in Figure 8-6.

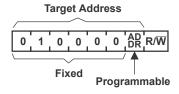


Figure 8-6. TCA6416A Address

Table 8-3. Address Reference

ADDR	I ² C BUS TARGET ADDRESS
L	32 (decimal), 20 (hexadecimal)
Н	33 (decimal), 21 (hexadecimal)

The last bit of the target address defines the operation (read or write) to be performed. A high (1) selects a read operation, while a low (0) selects a write operation.

8.6.2 Control Register and Command Byte

Following the successful acknowledgment of the address byte, the bus controller sends a command byte, which is stored in the control register in the TCA6416A. Three bits of this data byte state the operation (read or write) and the internal registers (input, output, polarity inversion, or configuration) that will be affected. This register can be written or read through the I²C bus. The command byte is sent only during a write transmission.

Once a new command has been sent, the register that was addressed continues to be accessed by reads until a new command byte has been sent.

Figure 8-7. Control Register Bits

Table 8-4. Command Byte

		CONTR	OL RE	GISTE	R BITS	3		COMMAND BYTE REGISTER		PROTOCOL	POWER-UP
B7	В6	B5	B4	В3	B2	B1	В0	(HEX)	REGISTER	PROTOCOL	DEFAULT
0	0	0	0	0	0	0	0	00	Input Port 0	Read byte	xxxx xxxx ⁽¹⁾
0	0	0	0	0	0	0	1	01	Input Port 1	Read byte	xxxx xxxx ⁽¹⁾
0	0	0	0	0	0	1	0	02	Output Port 0	Read/write byte	1111 1111
0	0	0	0	0	0	1	1	03	Output Port 1	Read/write byte	1111 1111
0	0	0	0	0	1	0	0	04	Polarity Inversion 0	Read/write byte	0000 0000
0	0	0	0	0	1	0	1	05	Polarity Inversion 1	Read/write byte	0000 0000
0	0	0	0	0	1	1	0	06	Configuration 0	Read/write byte	1111 1111
0	0	0	0	0	1	1	1	07	Configuration 1	Read/write byte	1111 1111

⁽¹⁾ Undefined

8.6.3 Register Descriptions

The Input Port registers (registers 0 and 1) reflect the incoming logic levels of the pins, regardless of whether the pin is defined as an input or an output by the Configuration register. They act only on read operation. Writes to these registers have no effect. The default value (X) is determined by the externally applied logic level. Before a read operation, a write transmission is sent with the command byte to indicate to the I²C device that the Input Port register will be accessed next.

Table 8-5. Registers 0 and 1 (Input Port Registers)

		_		٠.		•	,	
BIT	I-07	I-06	I-05	I-04	I-03	I-02	I-01	I-00
DEFAULT	Х	Х	Х	Х	Х	Х	Х	Х
BIT	I-17	I-16	I-15	I-14	I-13	I-12	I-11	I-10
DEFAULT	Х	Х	Х	Х	Х	Х	Х	Х

The Output Port registers (registers 2 and 3) shows the outgoing logic levels of the pins defined as outputs by the Configuration register. Bit values in these registers have no effect on pins defined as inputs. In turn, reads from these registers reflect the value that is in the flip-flop controlling the output selection, not the actual pin value.

Table 8-6. Registers 2 and 3 (Output Port Registers)

BIT	O-07	O-06	O-05	O-04	O-03	O-02	O-01	O-00
DEFAULT	1	1	1	1	1	1	1	1
BIT	O-17	O-16	O-15	O-14	O-13	O-12	O-11	O-10
DEFAULT	1	1	1	1	1	1	1	1

The Polarity Inversion registers (register 4 and 5) allow polarity inversion of pins defined as inputs by the Configuration register. If a bit in these registers is set (written with 1), the corresponding port pin's polarity is inverted. If a bit in these registers is cleared (written with a 0), the corresponding port pin's original polarity is retained.

Table 8-7. Registers 4 and 5 (Polarity Inversion Registers)

		_					,	
BIT	P-07	P-06	P-05	P-04	P-03	P-02	P-01	P-00
DEFAULT	0	0	0	0	0	0	0	0

Table 8-7. Registers 4 and 5	(Polarity	v Inversion	Registers)	(continued)
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				•		, ,	•	
BIT	P-17	P-16	P-15	P-14	P-13	P-12	P-11	P-10
DEFAULT	0	0	0	0	0	0	0	0

The Configuration registers (registers 6 and 7) configure the direction of the I/O pins. If a bit in these registers is set to 1, the corresponding port pin is enabled as an input with a high-impedance output driver. If a bit in these registers is cleared to 0, the corresponding port pin is enabled as an output.

Table 8-8. Registers 6 and 7 (Configuration Registers)

BIT	C-07	C-06	C-05	C-04	C-03	C-02	C-01	C-00
DEFAULT	1	1	1	1	1	1	1	1
BIT	C-17	C-16	C-15	C-14	C-13	C-12	C-11	C-10
DEFAULT	1	1	1	1	1	1	1	1

8.6.4 Bus Transactions

Data is exchanged between the controller and TCA6416A through write and read commands.

8.6.4.1 Writes

Data is transmitted to the TCA6416A by sending the device address and setting the least-significant bit (LSB) to a logic 0 (see Figure 8-6 for device address). The command byte is sent after the address and determines which register receives the data that follows the command byte. There is no limitation on the number of data bytes sent in one write transmission.

The eight registers within the TCA6416A are configured to operate as four register pairs. The four pairs are input ports, output ports, polarity inversion ports and configuration ports. After sending data to one register, the next data byte is sent to the other register in the pair (see Figure 8-8 and Figure 8-9). For example, if the first byte is send to Output Port 1 (register 3), the next byte is stored in Output Port 0 (register 2).

There is no limitation on the number of data bytes sent in one write transmission. In this way, each 8-bit register may be updated independently of the other registers.

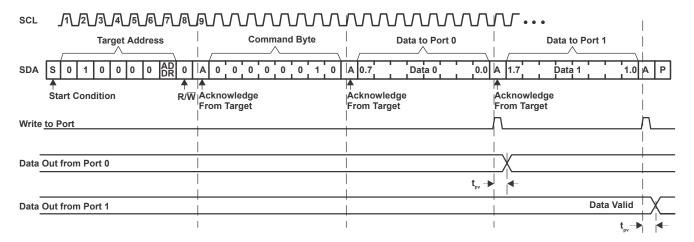


Figure 8-8. Write to Output Port Register

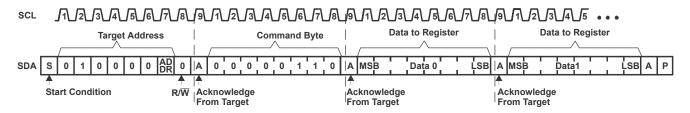


Figure 8-9. Write to Configuration or Polarity Inversion Registers

8.6.4.2 Reads

The bus controller first must send the TCA6416A address with the LSB set to a logic 0 (see Figure 8-6 for device address). The command byte is sent after the address and determines which register is accessed.

After a restart, the device address is sent again but, this time, the LSB is set to a logic 1. Data from the register defined by the command byte then is sent by the TCA6416A (see Figure 8-10 and Figure 8-11).

After a restart, the value of the register defined by the command byte matches the register being accessed when the restart occurred. For example, if the command byte references Input Port 1 before the restart, and the restart occurs when Input Port 0 is being read, the stored command byte changes to reference Input Port 0. The original command byte is forgotten. If a subsequent restart occurs, Input Port 0 is read first. Data is clocked into the register on the rising edge of the ACK clock pulse. After the first byte is read, additional bytes may be read, but the data now reflects the information in the other register in the pair. For example, if Input Port 1 is read, the next byte read is Input Port 0.

Data is clocked into the register on the rising edge of the ACK clock pulse. There is no limitation on the number of data bytes received in one read transmission, but when the final byte is received, the bus controller must not acknowledge the data.

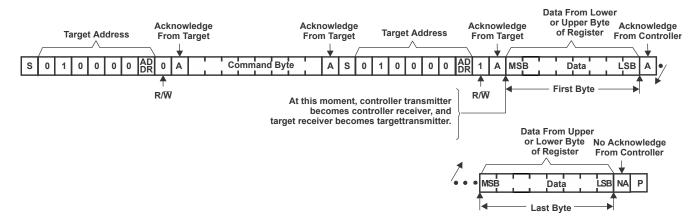
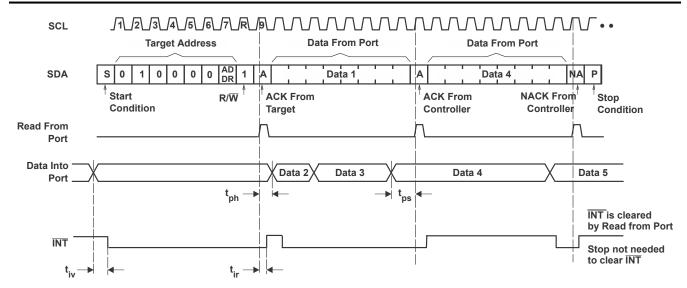


Figure 8-10. Read From Register



- A. Transfer of data can be stopped at any time by a Stop condition. When this occurs, data present at the latest acknowledge phase is valid (output mode). It is assumed that the command byte previously has been set to 00 (read Input Port register).
- B. This figure eliminates the command byte transfer, a restart, and target address call between the initial target address call and actual data transfer from P port (see Figure 8-10).

Figure 8-11. Read Input Port Register

9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

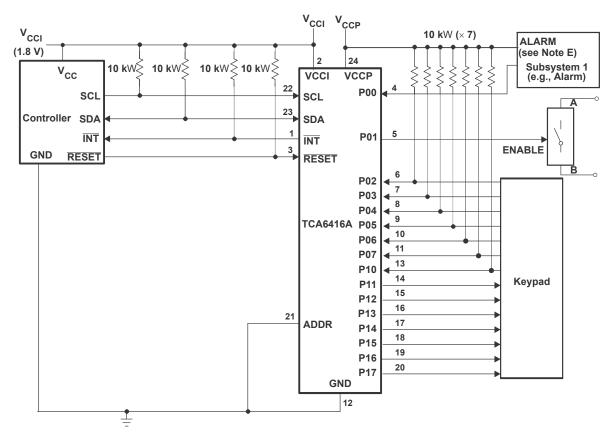
9.1 Application Information

Applications of the TCA6416A will have this device connected as a target to an I2C controller (processor), and the I2C bus may contain any number of other target devices. The TCA6416A will be in a remote location from the controller, placed close to the GPIOs to which the controller needs to monitor or control.

A typical application of the TCA6416A will operate with a lower voltage on the controller side (VCCI), and a higher voltage on the P-port side (VCCP). The P-ports can be configured as outputs connected to inputs of devices such as enable, reset, power select, the gate of a switch, and LEDs. The P-ports can also be configured as inputs to receive data from interrupts, alarms, status outputs, or push buttons.

9.2 Typical Application

Figure 9-1 shows an application in which the TCA6416A can be used.



- A. Device address configured as 0100000 for this example.
- B. P00 and P02-P10 are configured as inputs.
- C. P01 and P11-P17 are configured as outputs.
- D. Pin numbers shown are for the PW package.

E. Resistors are required for inputs (on P port) that may float. If a driver to an input will never let the input float, a resistor is not needed. Outputs (in the P port) do not need pullup resistors.

Figure 9-1. Typical Application Schematic

9.2.1 Design Requirements

Table 9-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
I ² C input voltage (V _{CCI})	1.8 V
P-port input/output voltage (V _{CCP})	5 V
Output current rating, P-port sinking (I _{OL})	25 mA
Output current rating, P-port sourcing (I _{OH})	10 mA
I ² C bus clock (SCL) speed	400 kHz

9.2.2 Detailed Design Procedure

The pull-up resistors, R_P , for the SCL and SDA lines need to be selected appropriately and take into consideration the total capacitance of all targets on the I^2C bus. The minimum pull-up resistance is a function of V_{CC} , $V_{OL,(max)}$, and I_{OL} :

$$R_{p(min)} = \frac{V_{CC} - V_{OL(max)}}{I_{OL}}$$
(1)

The maximum pull-up resistance is a function of the maximum rise time, t_r (300 ns for fast-mode operation, f_{SCL} = 400 kHz) and bus capacitance, C_b :

$$R_{p(max)} = \frac{t_r}{0.8473 \times C_b}$$
(2)

The maximum bus capacitance for an I^2C bus must not exceed 400 pF for standard-mode or fast-mode operation. The bus capacitance can be approximated by adding the capacitance of the TCA9538, C_i for SCL or C_{io} for SDA, the capacitance of wires/connections/traces, and the capacitance of additional targets on the bus.

9.2.2.1 Minimizing I_{CC} When I/Os Control LEDs

When the I/Os are used to control LEDs, normally they are connected to V_{CC} through a resistor as shown in Figure 9-2. For a P-port configured as an input, I_{CC} increases as V_I becomes lower than V_{CC} . The LED is a diode, with threshold voltage V_T , and when a P-port is configured as an input the LED will be off but V_I is a V_T drop below V_{CC} .

For battery-powered applications, it is essential that the voltage of P-ports controlling LEDs is greater than or equal to V_{CC} when the P-ports are configured as input to minimize current consumption. Figure 9-2 shows a high-value resistor in parallel with the LED. Figure 9-3 shows V_{CC} less than the LED supply voltage by at least V_T . Both of these methods maintain the I/O V_I at or above V_{CC} and prevents additional supply current consumption when the P-port is configured as an input and the LED is off.

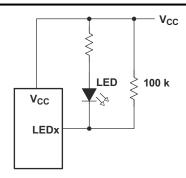


Figure 9-2. High-Value Resistor in Parallel With LED

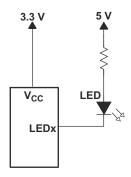


Figure 9-3. Device Supplied by a Lower Voltage

9.2.3 Application Curves

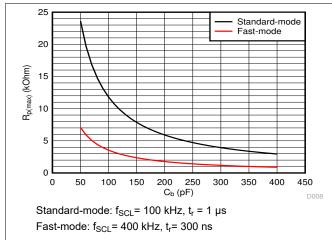


Figure 9-4. Maximum Pullup Resistance $(R_{p(max)})$ vs Bus Capacitance (C_b)

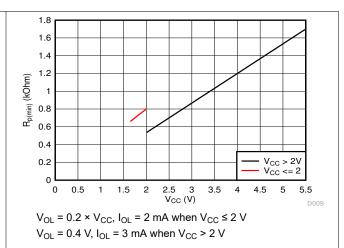


Figure 9-5. Minimum Pullup Resistance ($R_{p(min)}$) vs Pullup Reference Voltage (V_{CC})

10 Power Supply Recommendations

10.1 Power-On Reset Requirements

In the event of a glitch or data corruption, TCA6416A can be reset to its default conditions by using the power-on reset feature. Power-on reset requires that the device go through a power cycle to be completely reset. This reset also happens when the device is powered on for the first time in an application.

Ramping up the device V_{CCP} before V_{CCI} is recommended to prevent SDA from potentially being stuck LOW.

The two types of power-on reset are shown in Figure 10-1 and Figure 10-2.

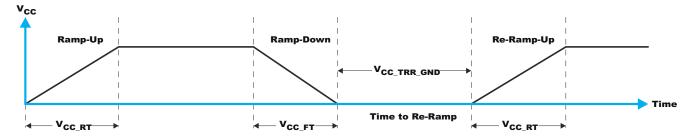


Figure 10-1. V_{CC} is Lowered Below 0.2 V or 0 V and Then Ramped up to V_{CC}

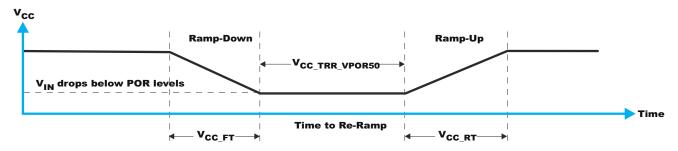


Figure 10-2. V_{CC} is Lowered Below the POR Threshold, Then Ramped Back up to V_{CC}

Table 10-1 specifies the performance of the power-on reset feature for TCA6416A for both types of power-on reset.

	PARAMETER ⁽¹⁾ (2)	MIN	TYP	MAX	UNIT	
t _{FT}	Fall rate	See Figure 10-1	0.1	;	2000	ms
t _{RT}	Rise rate	See Figure 10-1	0.1	;	2000	ms
t _{TRR_GND}	Time to re-ramp (when V _{CC} drops to GND)	See Figure 10-1	1			μs
t _{TRR_POR50}	Time to re-ramp (when V _{CC} drops to V _{POR_MIN} – 50 mV)	See Figure 10-2	1			μs
V _{CC_GH}	Level that V_{CCP} can glitch down to, but not cause a functional disruption when V_{CCX_GW} = 1 μs	See Figure 10-3			1.2	V
t _{GW}	Glitch width that will not cause a functional disruption when $V_{CCX_GH} = 0.5 \times V_{CCx}$	See Figure 10-3			10	μs
V _{PORF}	Voltage trip point of POR on falling V _{CC}		0.7			V
V _{PORR}	Voltage trip point of POR on rising V _{CC}				1.4	V

Table 10-1. Recommended Supply Sequencing and Ramp Rates

(2) Not tested. Specified by design.Glitches in the power supply can also affect the power-on reset performance of this de

⁽¹⁾ $T_A = 25$ °C (unless otherwise noted).

Glitches in the power supply can also affect the power-on reset performance of this device. The glitch width (V_{CC_GW}) and height (V_{CC_GH}) are dependent on each other. The bypass capacitance, source impedance, and device impedance are factors that affect power-on reset performance. Figure 10-3 and Table 10-1 provide more information on how to measure these specifications.



Figure 10-3. Glitch Width and Glitch Height

 V_{POR} is critical to the power-on reset. V_{POR} is the voltage level at which the reset condition is released and all the registers and the I²C/SMBus state machine are initialized to the default states. The value of V_{POR} differs based on the V_{CC} being lowered to or from 0. Figure 10-4 and Table 10-1 provide more details on this specification.

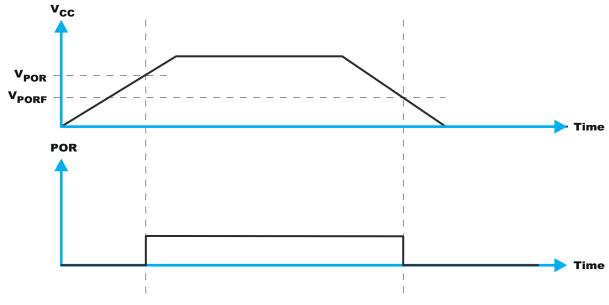


Figure 10-4. V_{POR}

11 Layout

11.1 Layout Guidelines

For printed circuit board (PCB) layout of the TCA6416A, common PCB layout practices should be followed but additional concerns related to high-speed data transfer such as matched impedances and differential pairs are not a concern for I²C signal speeds.

In all PCB layouts, it is a best practice to avoid right angles in signal traces, to fan out signal traces away from each other upon leaving the vicinity of an integrated circuit (IC), and to use thicker trace widths to carry higher amounts of current that commonly pass through power and ground traces. By-pass and de-coupling capacitors are commonly used to control the voltage on the VCCP pin, using a larger capacitor to provide additional power in the event of a short power supply glitch and a smaller capacitor to filter out high-frequency ripple. These capacitors should be placed as close to the TCA6416A as possible. These best practices are shown in Figure 11-1.

For the layout example provided in Figure 11-1, it would be possible to fabricate a PCB with only 2 layers by using the top layer for signal routing and the bottom layer as a split plane for power (V_{CCI} and V_{CCP}) and ground (GND). However, a 4 layer board is preferable for boards with higher density signal routing. On a 4 layer PCB, it is common to route signals on the top and bottom layer, dedicate one internal layer to a ground plane, and dedicate the other internal layer to a power plane. In a board layout using planes or split planes for power and ground, vias are placed directly next to the surface mount component pad which needs to attach to V_{CCI} , V_{CCP} , or GND and the via is connected electrically to the internal layer or the other side of the board. Vias are also used when a signal trace needs to be routed to the opposite side of the board, but this technique is not demonstrated in Figure 11-1.

11.2 Layout Example

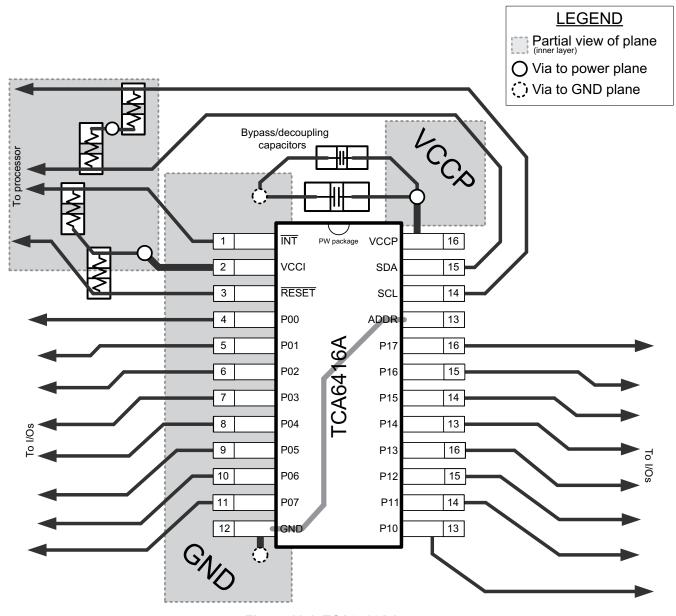


Figure 11-1. TCA6416A Layout

12 Device and Documentation Support

12.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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12.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
TCA6416APWR	Active	Production	TSSOP (PW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PH416A
TCA6416APWR.A	Active	Production	TSSOP (PW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PH416A
TCA6416APWRG4.A	Active	Production	TSSOP (PW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PH416A
TCA6416ARTWR	Active	Production	WQFN (RTW) 24	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PH416A
TCA6416ARTWR.A	Active	Production	WQFN (RTW) 24	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PH416A
TCA6416ARTWR.B	Active	Production	WQFN (RTW) 24	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PH416A
TCA6416ARTWRG4.A	Active	Production	WQFN (RTW) 24	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PH416A
TCA6416ARTWRG4.B	Active	Production	WQFN (RTW) 24	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PH416A

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

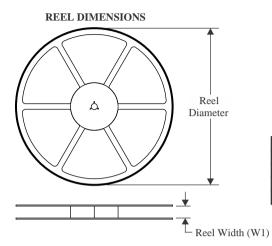
PACKAGE OPTION ADDENDUM

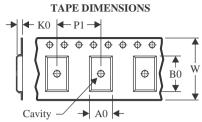
	23-May-2025
o event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an ann	nual basis.

PACKAGE MATERIALS INFORMATION

13-May-2025

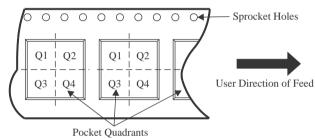
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

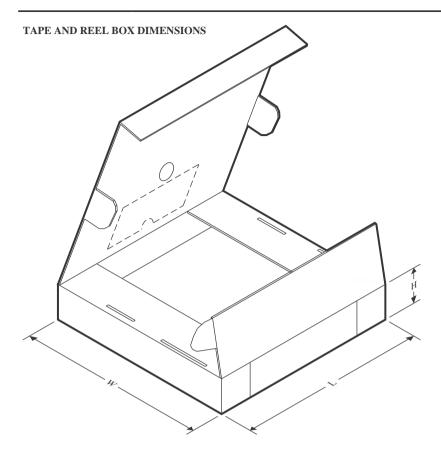


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TCA6416ARTWR	WQFN	RTW	24	3000	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2
TCA6416ARTWR	WQFN	RTW	24	3000	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2

PACKAGE MATERIALS INFORMATION

13-May-2025



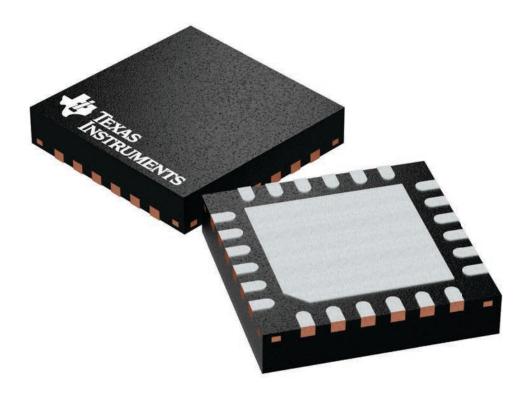
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TCA6416ARTWR	WQFN	RTW	24	3000	367.0	367.0	35.0
TCA6416ARTWR	WQFN	RTW	24	3000	356.0	356.0	35.0

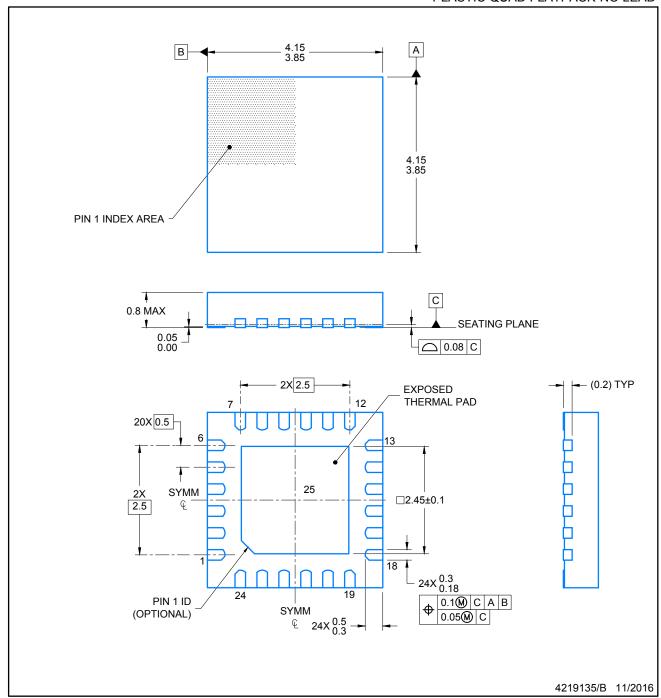
4 x 4, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



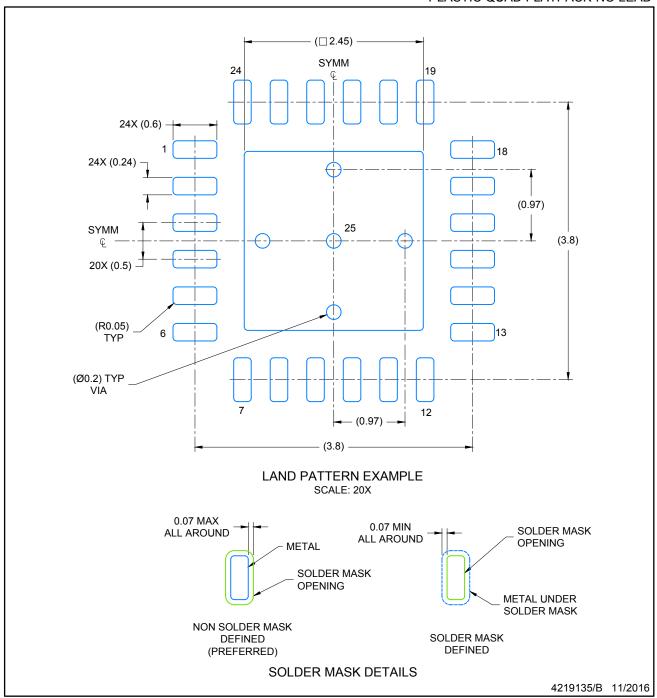
PLASTIC QUAD FLATPACK-NO LEAD



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.

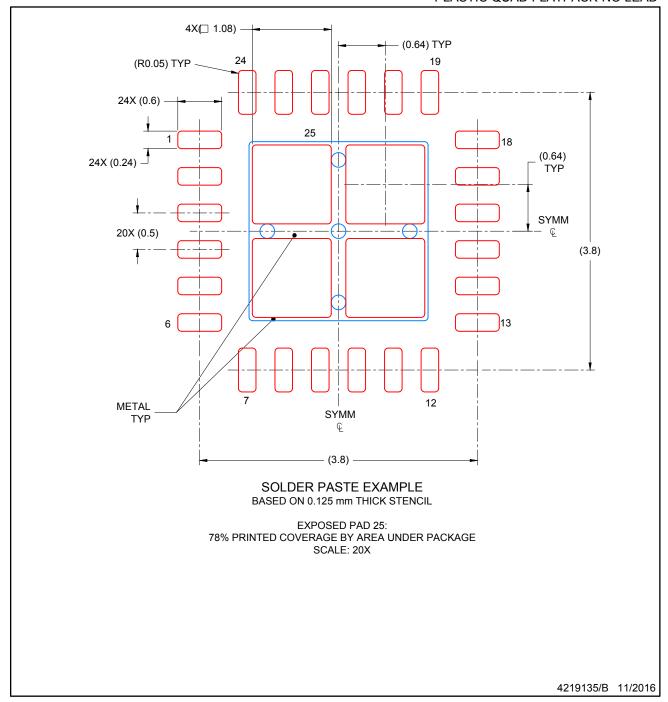
PLASTIC QUAD FLATPACK-NO LEAD



NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

PLASTIC QUAD FLATPACK-NO LEAD

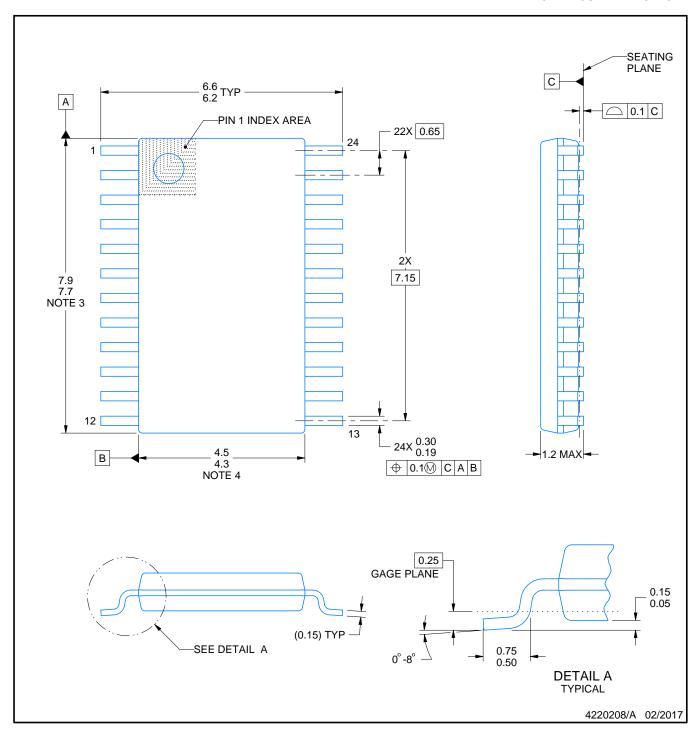


NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



SMALL OUTLINE PACKAGE



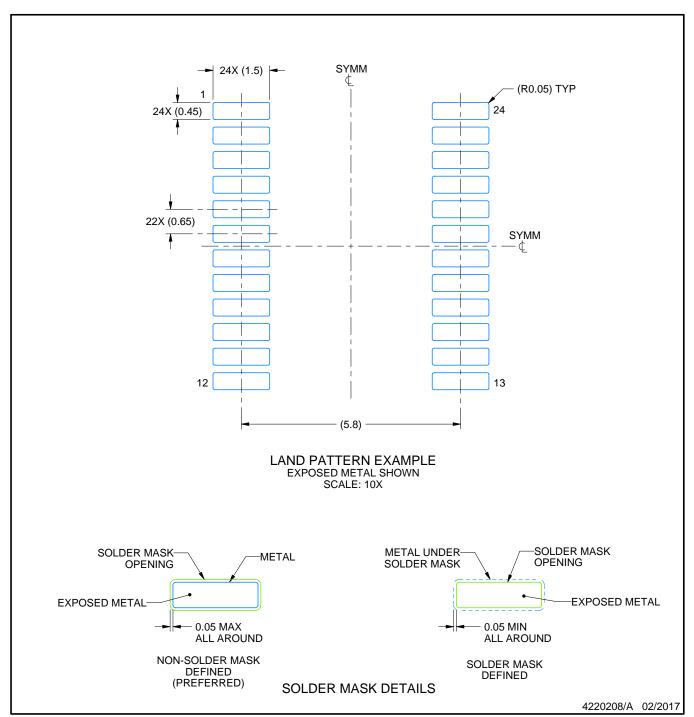
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.